

# FUJI WEB SIMULATION TOOL: PLECS BASED POWER ELECTRONIC APPLICATION SIMULATOR

## USER MANUAL

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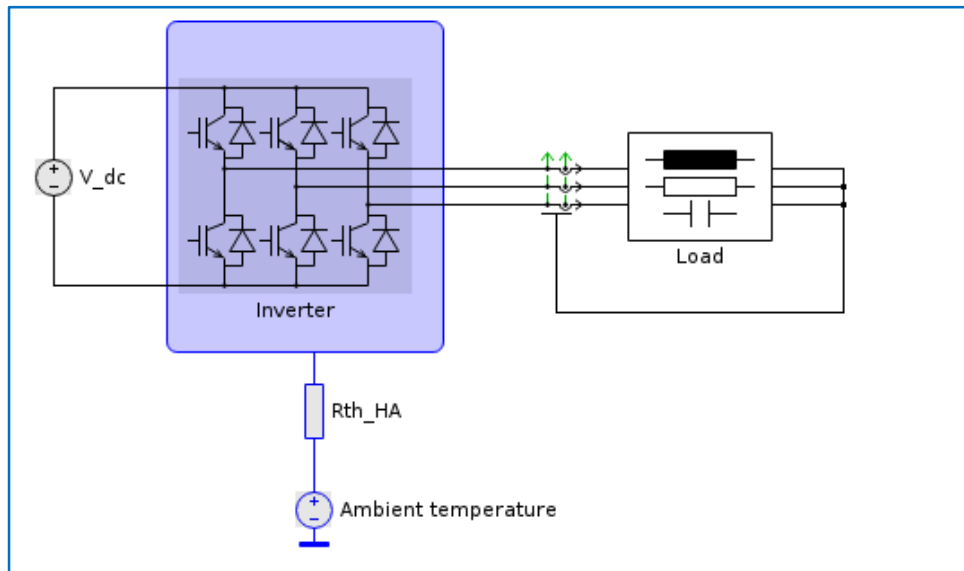
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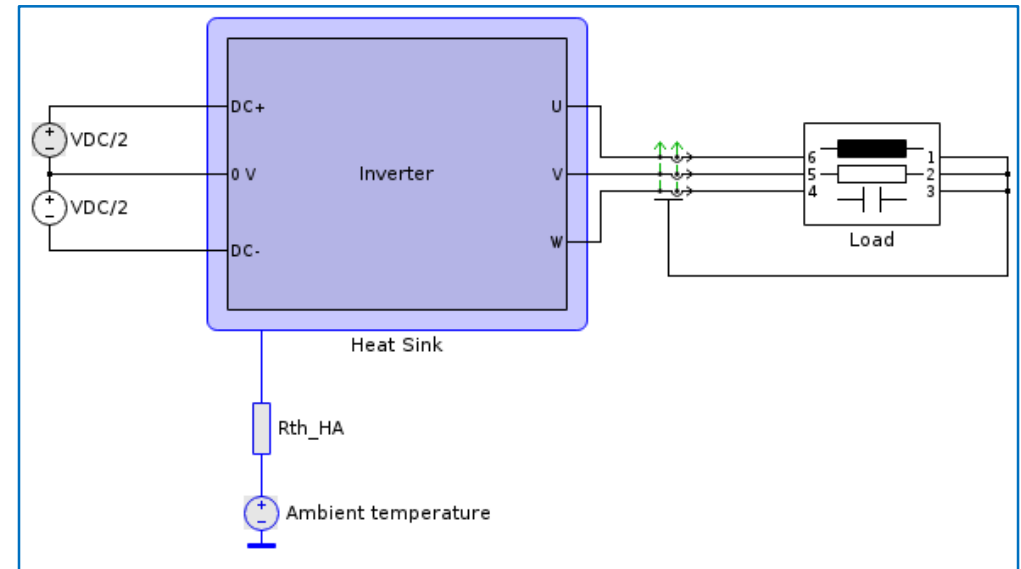
<b>1. How to Start</b>	<b>p.4</b>
<b>2. 3 Phases 2 Level Inverter</b>	<b>p.5</b>
<b>3. Thermal Conditions</b>	<b>p.8</b>
<b>4. Electrical Conditions</b>	<b>p.10</b>
<b>5. 3 Level T Type Inverter</b>	<b>p.11</b>
<b>6. Module Selection</b>	<b>p.15</b>
<b>7. PWM Methods</b>	<b>p.16</b>
<b>8. Simulation</b>	<b>p.17</b>
<b>9. Scope Functions</b>	<b>p.21</b>

Choose between two different models:

## 3 Phases 2 Level Inverter



## 3 Level T type Inverter



[http://simu.fujielectric-europe.com/2\\_level\\_inverter.html](http://simu.fujielectric-europe.com/2_level_inverter.html)

[http://simu.fujielectric-europe.com/3\\_level\\_inverter\\_t\\_type.html](http://simu.fujielectric-europe.com/3_level_inverter_t_type.html)

# 3 Phases 2 Level Inverter

## Explanation of start page

### Variable Parameters for Simulation

Modulation rate:

Modulation strategy:

Inverter output current:  A

Inverter output frequency:  Hz

Switching frequency:  Hz

Power factor:

### Module Selection

Module type:

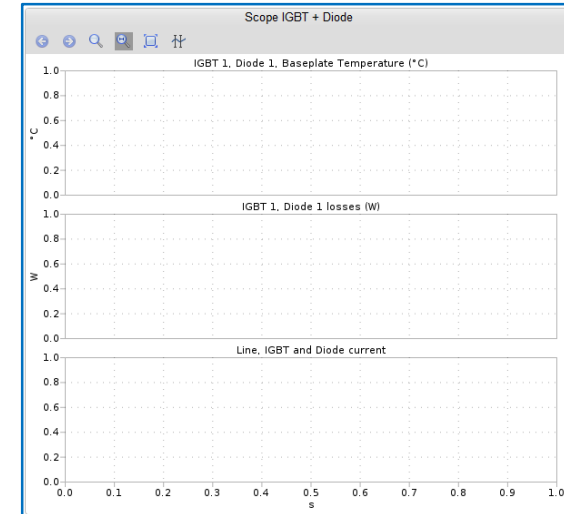
Blocking voltage:

Package:

IGBT Module:

- [1MBI1200VC-120P](#) V Series, 1200 A
- [1MBI1600VC-120P](#) V Series, 1600 A
- [1MBI2400VC-120P](#) V Series, 2400 A
- [1MBI2400VD-120P](#) V Series, 2400 A
- [1MBI3600VD-120P](#) V Series, 3600 A

### Scope



### Numerical results from Scope

Temperatures					
	Max temperature	Min temperature	Avg temperature		
IGBT					
Diode					
Case					
Heat sink					
Losses					
	Cond. losses	Turn-on losses	Turn-off losses	Reverse recovery losses	Total losses
IGBT					
Diode					

# Variables Parameters in the Circuit

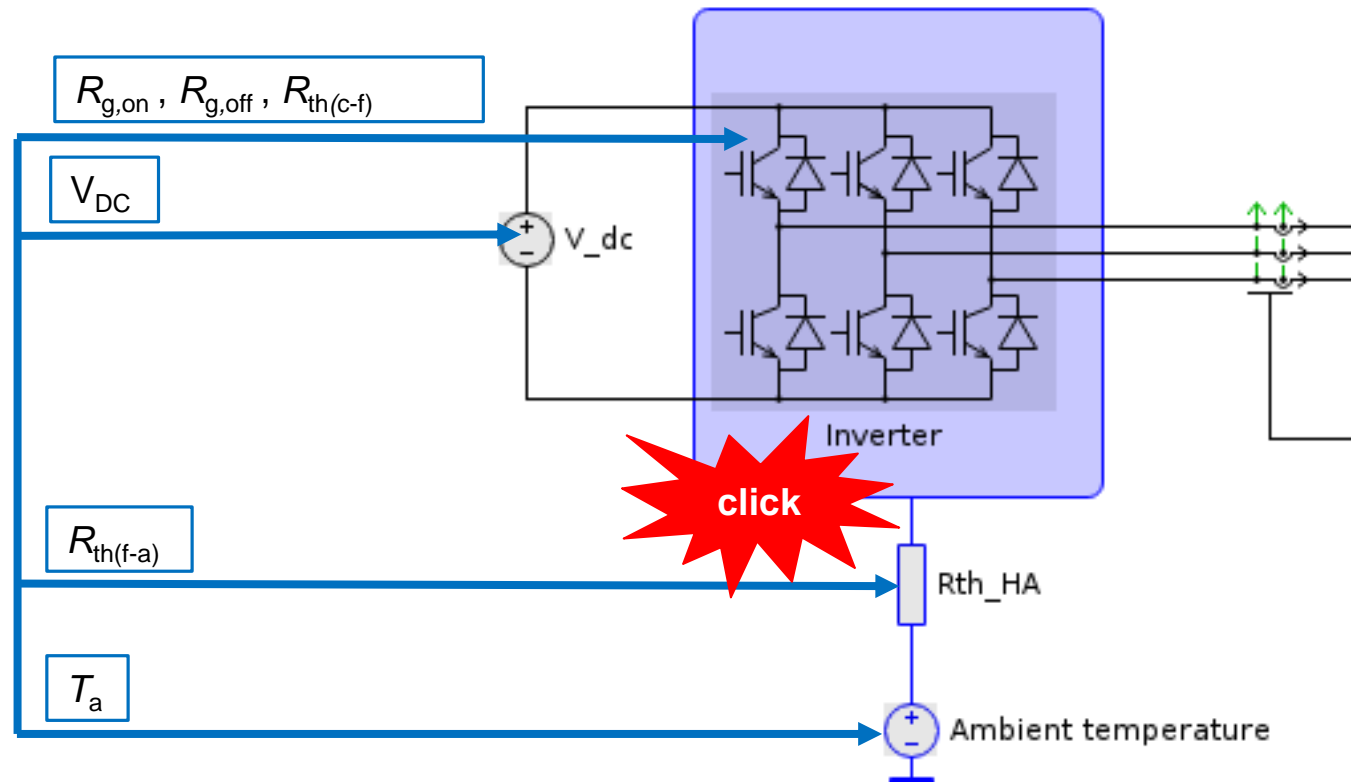
Components highlighted in **grey** contain adjustable parameters

## Thermal Settings

- $R_{th(c-f)}$  case to heat sink
- $R_{th(f-a)}$  heat sink to ambient
- Ambient temperature  $T_a$

## Electrical Settings

- $R_{g,on}$  and  $R_{g,off}$
- $V_{dc}$



Different scenarios in the thermal calculation can be considered:

## 1) Calculate case temperature

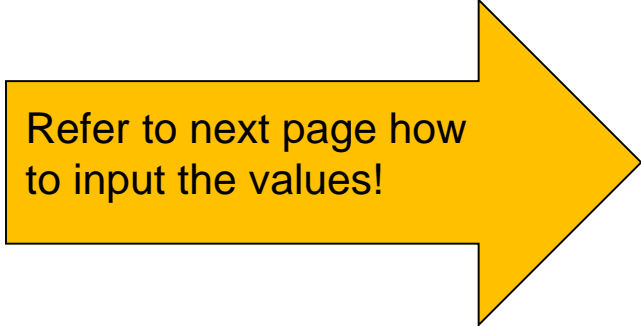
- Input  $R_{th(c-f)}$
- Input  $R_{th(f-a)}$
- Set ambient temperature

## 2) Fixed case temperature

- $R_{th(c-f)} = R_{th(f-a)} = 0$
- Set ambient temperature

## 3) Fixed heat sink temperature

- Set  $R_{th(f-a)} = 0$
- Set heat sink temperature = ambient temperature
- Provide  $R_{th\_c-h}$



Refer to next page how to input the values!

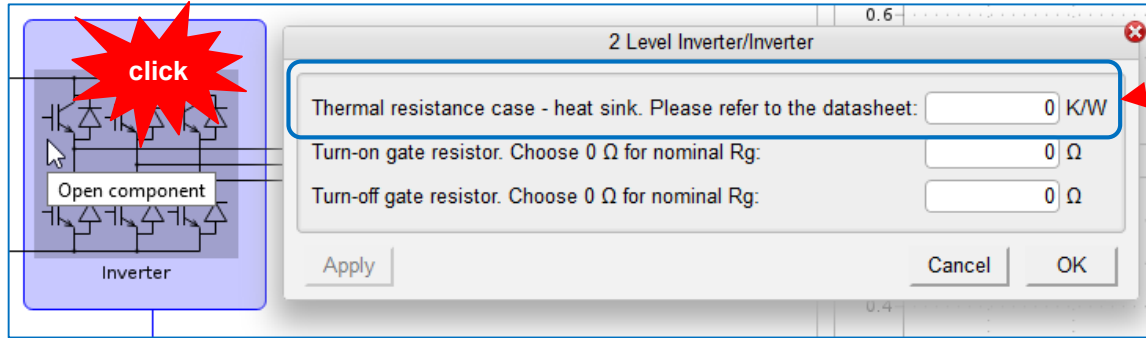


# Thermal Conditions: Settings

$$R_{th(c-f)}$$

Click on the grey box in the inverter model.

A drop down menu will open.

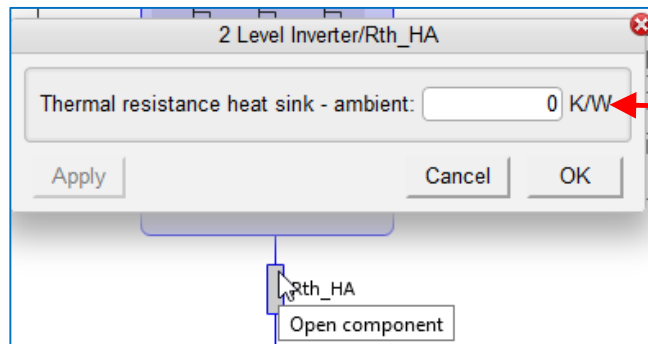


Input  $R_{th(c-f)}$  here.

Please check the datasheet for the value.

$$R_{th(h-a)}$$

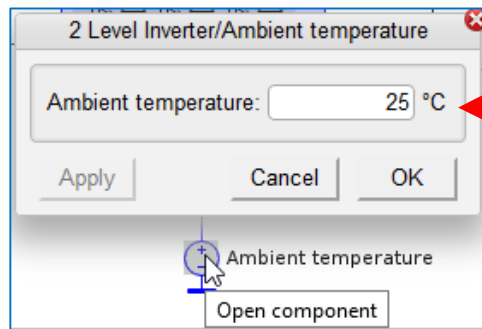
Click on the resistor "Rth\_HA"



Input  $R_{th(h-a)}$  here.

$$T_a$$

Click on the constant temperature symbol "Ambient temperature"



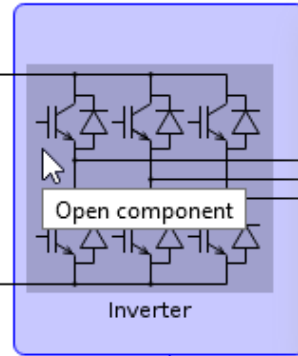
Input ambient temperature.

# Electrical Conditions

## $R_{g,on}$ and $R_{g,off}$

Click on the grey inverter part and the menu will open.

Input  $R_{g,on}$  and  $R_{g,off}$ . Set them to 0 if you want to use the datasheet values.



2 Level Inverter/Inverter

Thermal resistance case - heat sink. Please refer to the datasheet:  K/W

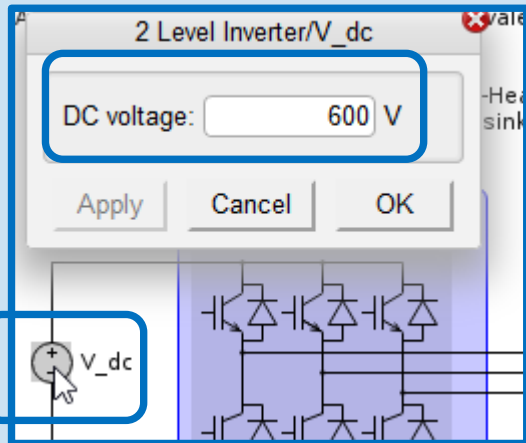
Turn-on gate resistor. Choose 0 Ω for nominal Rg:  Ω

Turn-off gate resistor. Choose 0 Ω for nominal Rg:  Ω

Apply Cancel OK

## $V_{DC}$

Drop Down Menu when clicking on the voltage source "V\_dc".



## $m$ , PWM, $I_{out}$ , $f_{out}$ , $f_{sw}$ , pf

Input the simulation parameters.

Modulation rate:

Modulation strategy:

Inverter output current:  A

Inverter output frequency:  Hz

Switching frequency:  Hz

Power factor:

# 3 Level T Type Inverter

# Variables Parameters in the Circuit

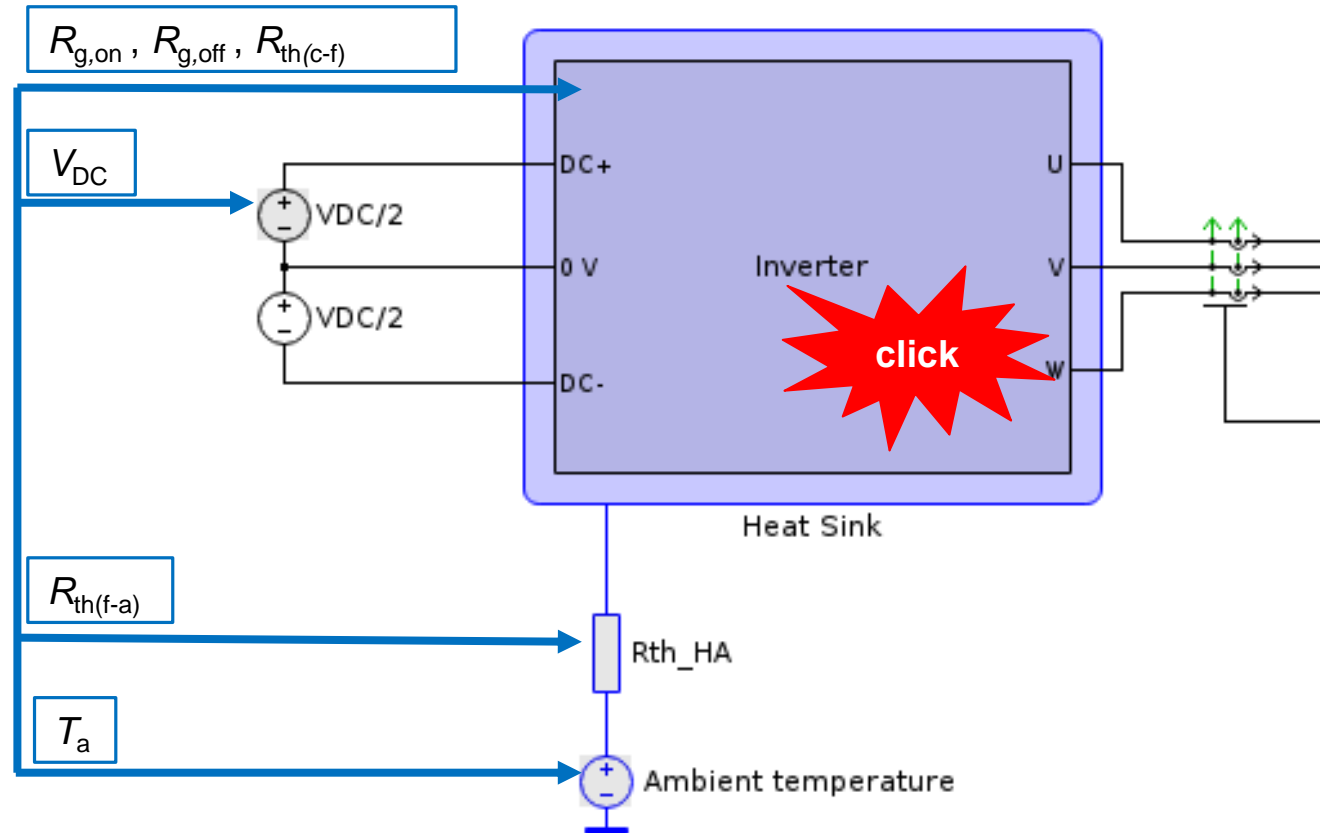
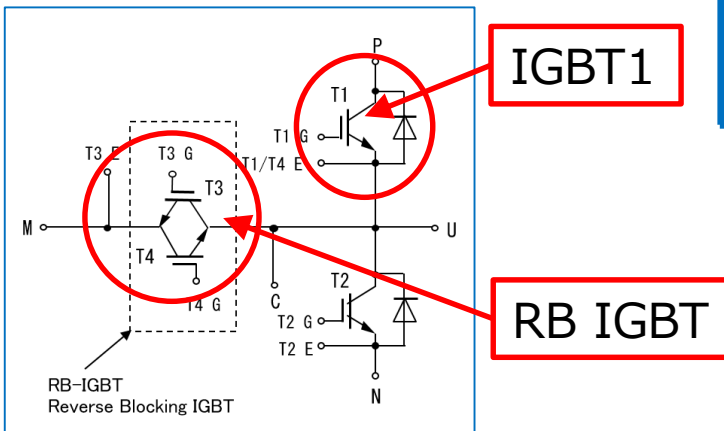
Components highlighted in **grey** contain adjustable parameters

## Thermal Settings

- $R_{th(c-f)}$  case to heat sink
- $R_{th(f-a)}$  heat sink to ambient
- Ambient temperature  $T_a$

## Electrical Settings

- IGBT1  $R_{g,on}$  and  $R_{g,off}$
- RB IGBT  $R_{g,on}$  and  $R_{g,off}$
- $V_{DC}$



# Electrical Conditions

## $R_{g,on}$ and $R_{g,off}$

Click on the grey inverter part and the menu will open.

Input  $R_{g,on}$  and  $R_{g,off}$  for IGBT and RB IGBT. Set them to 0 if you want to use the datasheet values.

Thermal resistance case - heat sink. Chose 0 K/W for fixed case temperature:  K/W

IGBT 1: Turn-on gate resistor. Chose 0  $\Omega$  for nominal Rg:   $\Omega$

IGBT 1: Turn-off gate resistor. Chose 0  $\Omega$  for nominal Rg:   $\Omega$

RB-IGBT: Turn-on gate resistor. Chose 0  $\Omega$  for nominal Rg:   $\Omega$

RB-IGBT: Turn-off gate resistor. Chose 0  $\Omega$  for nominal Rg:   $\Omega$

Buttons: Apply, Cancel, OK

## $V_{DC}$

Drop Down Menu when clicking on the voltage source "V\_DC/2".

DC voltage:  V

Buttons: Apply, Cancel, OK

## m, PWM, $I_{out}$ , $f_{out}$ , $f_{sw}$ , pf

Input the simulation parameters.

Modulation rate:

Modulation strategy:

Inverter output current:  A

Inverter output frequency:  Hz

Switching frequency:  kHz

Power factor:

## load

Choose load type.

Load:

IGBT Module:  [4MBI650VB-120R1-50](#) 1200 V, 650 A, Prime

# General Settings

# Module Selection

1  
Module type

Module type: Dual IGBT  
Blocking voltage: Single IGBT  
Package: 6 Pack  
IGBT Module: 6 Pack w. brake chopper

2  
Blocking voltage

Module type: Dual IGBT  
Blocking voltage: 1200 V  
Package: 600 V  
IGBT Module: 1200 V  
 [2MBI225VJ-120-50](#)

3  
Package

Module type: Dual IGBT  
Blocking voltage: 1200 V  
Package: Dual XT  
IGBT Module:  
 [2MBI225VJ-120-50](#)  
 [2MBI225VN-120-50](#)  
 [2MBI225VX-120-50](#)  
 [2MBI225XNA120-50](#)  
 [2MBI225XNB120-50](#)  
 [2MBI300VN-120-50](#)  
 [2MBI300VX-120-50](#)  
 [2MBI300XNA120-50](#)  
 [2MBI300XNB120-50](#)

4  
Modules

- IGBT Module:
- [2MBI225VJ-120-50](#) V Series, 225 A
  - [2MBI225VN-120-50](#) V Series, 225 A
  - [2MBI225VX-120-50](#) V Series, 225 A
  - [2MBI225XNA120-50](#) X Series, 225 A
  - [2MBI225XNB120-50](#) X Series, 225 A
  - [2MBI300VN-120-50](#) V Series, 300 A
  - [2MBI300VX-120-50](#) V Series, 300 A
  - [2MBI300XNA120-50](#) X Series, 300 A
  - [2MBI300XNB120-50](#) X Series, 300 A
  - [2MBI450VN-120-50](#) V Series, 450 A
  - [2MBI450VX-120-50](#) V Series, 450 A
  - [2MBI450XNA120-50](#) X Series, 450 A
  - [2MBI450XNB120-50](#) X Series, 450 A
  - [2MBI600VJ-120-50](#) V Series, 600 A
  - [2MBI600VN-120-50](#) V Series, 600 A
  - [2MBI600VX-120-50](#) V Series, 600 A
  - [2MBI600XNE120-50](#) X Series, 600 A
  - [2MBI600XNF120-50](#) X Series, 600 A
  - [2MBI600XNG120-50](#) X Series, 600 A
  - [2MBI600XNH120-50](#) X Series, 600 A
  - [2MBI800XNE120-50](#) X Series, 800 A
  - [2MBI800XNF120-50](#) X Series, 800 A

Link to data sheet on  
[www.fujielectric.com](http://www.fujielectric.com)

Currently the following modulation methods are available:

- Sinusoidal
- Sawtooth
- Space Vector
- 3<sup>rd</sup> harmonic injection

Modulation strategy:

Sinusoidal

Inverter output current:

Sinusoidal

Inverter output frequency:

Sawtooth

Switching frequency:

Space Vector

3rd harmonic injection

Open the drop down menu by clicking here.



# Run Simulation

- [2MBI600XNE120-50](#) X Series, 600 A
- [2MBI600XNF120-50](#) X Series, 600 A
- [2MBI600XNG120-50](#) X Series, 600 A
- [2MBI600XNH120-50](#) X Series, 600 A
- [2MBI800XNE120-50](#) X Series, 800 A
- [2MBI800XNF120-50](#) X Series, 800 A

Steady-State Analysis

Hold result

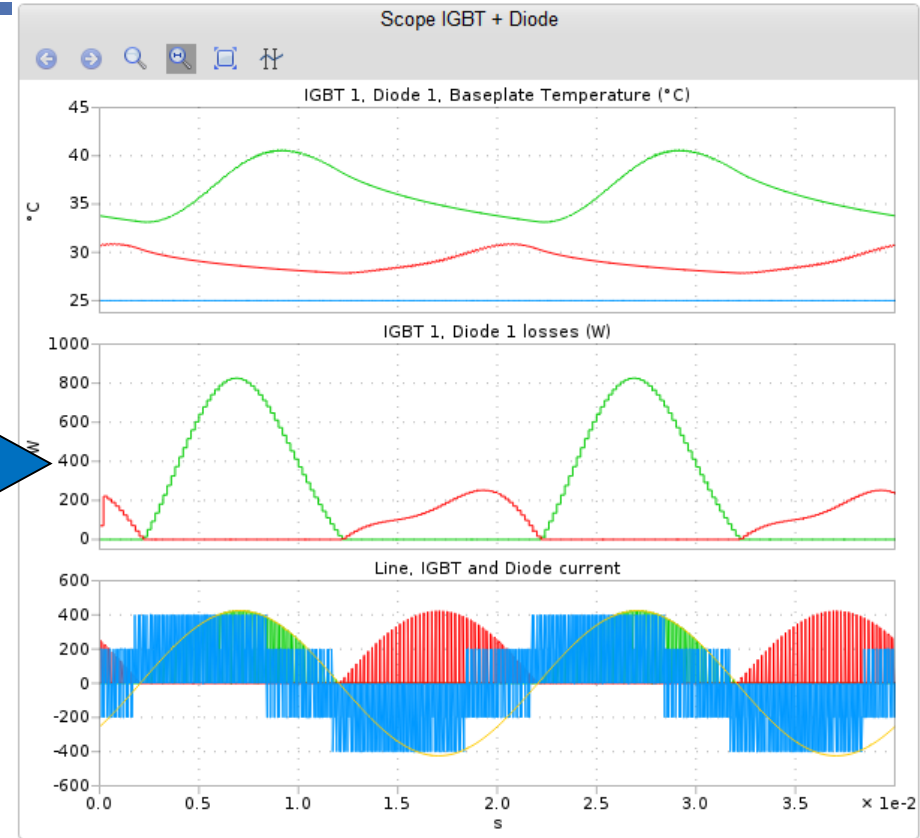
click

Simulation will start when you click the "Steady-State Analysis" button

The resulting waveforms will be displayed in the screen of the scope.

Corresponding numerical values are shown in the Temperatures / Losses windows.

Simulation Results

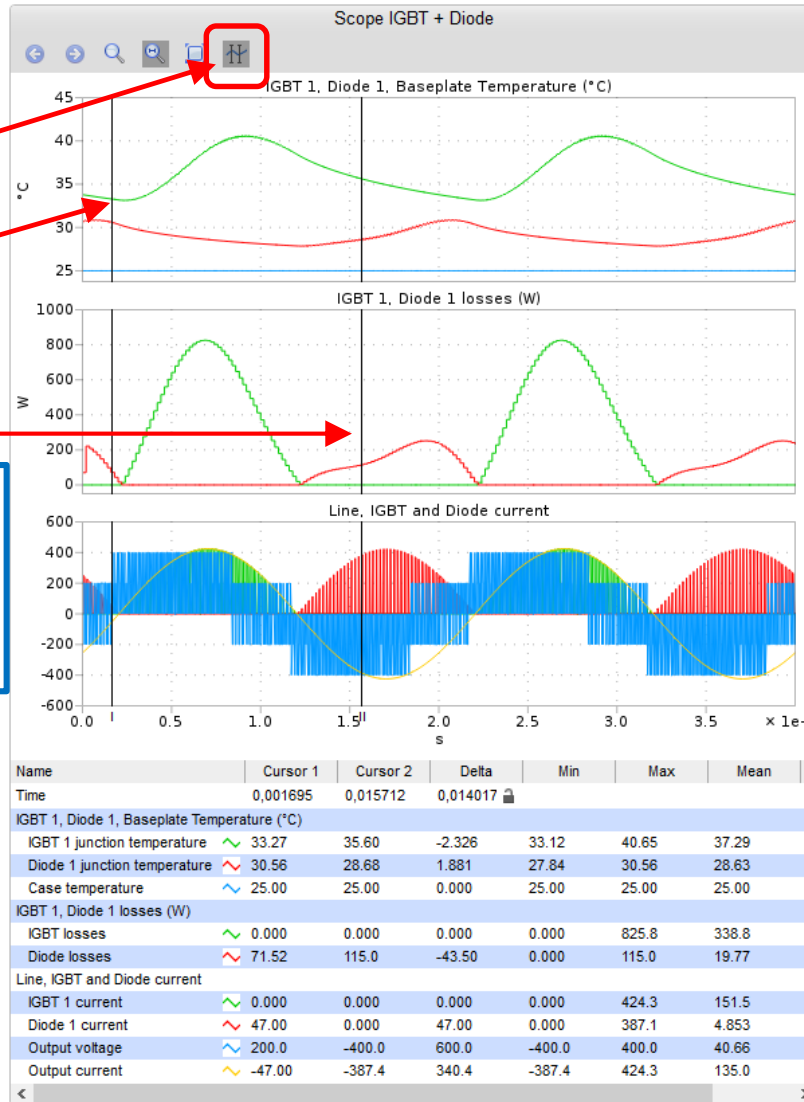


Temperatures			
	Max temperature	Min temperature	Avg temperature
IGBT	40.6 °C	33.1 °C	36.4 °C
Diode	30.9 °C	27.8 °C	29.0 °C
Case	25.0 °C		
Heat sink	25.0 °C		

Losses					
	Cond. losses	Turn-on losses	Turn-off losses	Reverse recovery losses	Total losses
IGBT	129.7 W	39.6 W	68.2 W		237.5 W
Diode	37.5 W			33.0 W	70.5 W

MT5F3988

# Simulation Results



Using Cursors

Cursors will firstly appear at the edges. Use mouse cursor to move them to the right position.

New window will open

## Analysis window:

### Characteristics

#### IGBT & Diode:

- T<sub>j</sub>, losses, current

#### Module:

- T<sub>c</sub>

#### Inverter:

- I<sub>out</sub>, V<sub>out</sub>

### Values

- Delta, min, max, mean, rms

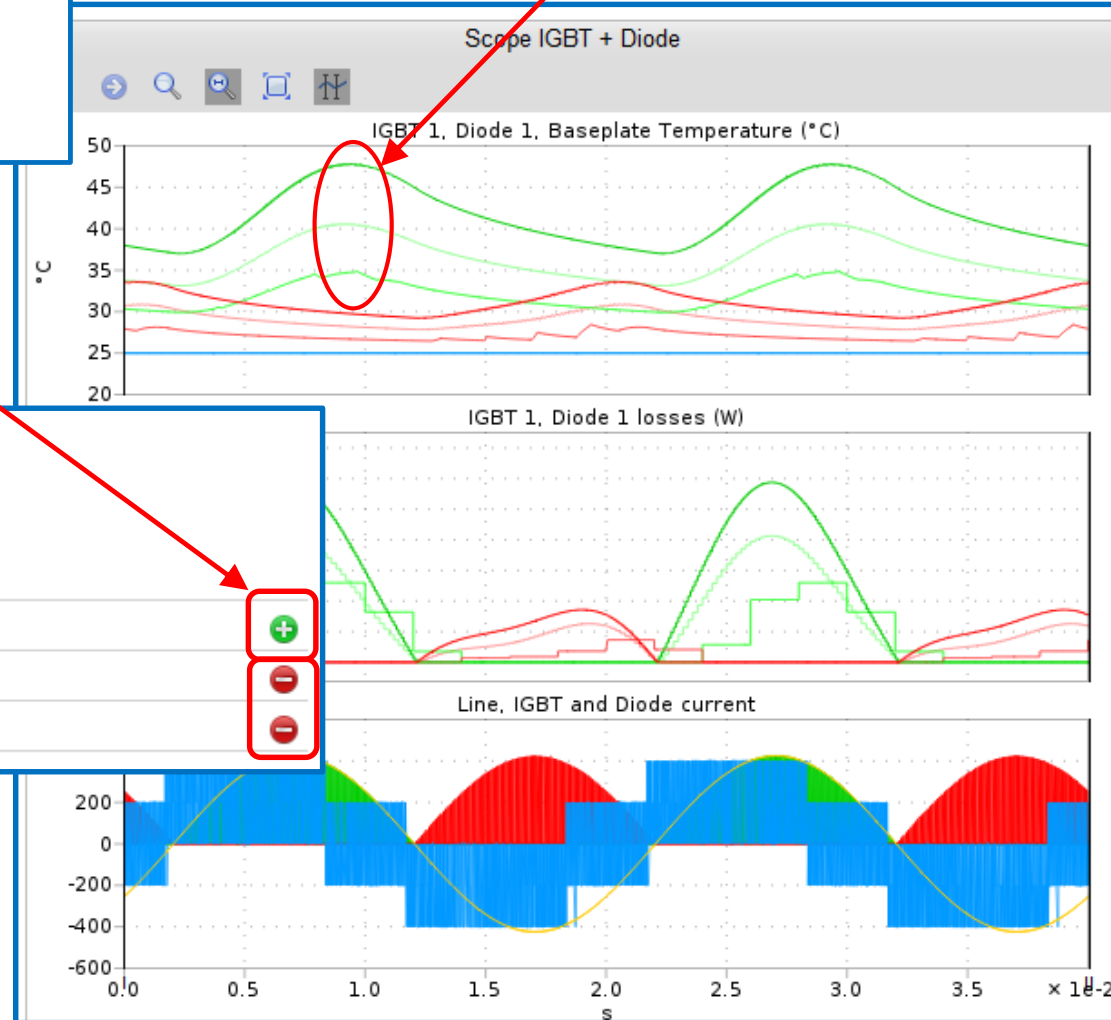
# Simulation Results: Comparison

Use „hold result“ to easily compare different simulations:

The first result will be kept automatically. For more please use **+** when the simulation is finished.

To remove a result from the history, please click **-**

3 different simulation results



Steady-State Analysis

Hold result

Analysis completed.

Result History

- Current Trace
- Trace 2
- Trace 1



# Comparison: Multiple results

Results of all 3 traces are displayed.

Scope values

Analysis result  
between the Cursors

Temperatures			
	Max temperature	Min temperature	Avg temperature
IGBT	47.8 °C	37.0 °C	41.8 °C
	34.9 °C	29.9 °C	31.9 °C
	40.6 °C	33.1 °C	36.4 °C
Diode	33.6 °C	29.2 °C	31.0 °C
	28.5 °C	26.5 °C	27.1 °C
	30.9 °C	27.8 °C	29.0 °C
Case	25.0 °C		
	25.0 °C		
	25.0 °C		
Heat sink	25.0 °C		
	25.0 °C		
	25.0 °C		

Losses					
	Cond. losses	Turn-on losses	Turn-off losses	Reverse recovery losses	Total losses
IGBT	130.5 W	82.1 W	137.4 W		350.0 W
	133.6 W	3.6 W	7.1 W		144.3 W
	129.7 W	39.6 W	68.2 W		237.5 W
Diode	37.8 W			67.8 W	105.7 W
	33.5 W			3.1 W	36.6 W
	37.5 W			33.0 W	70.5 W

Name	Cursor 1	Cursor 2	Delta	Min	Max	Mean	
Time	0,0054617	0,025726	0,020264				
IGBT 1, Diode 1, Baseplate Temperature (°C)							
IGBT 1 junction temperature	41.67	42.40	-0.7326	37.01	47.84	41.80	4
	31.90	32.20	-0.3025	29.92	34.91	31.93	3
	36.45	36.82	-0.3757	33.12	40.65	36.40	3
Diode 1 junction temperature	30.85	30.76	0.09595	29.23	33.62	31.02	3
	27.11	27.07	0.03669	26.47	28.46	27.08	2
	28.96	28.89	0.06622	27.84	30.90	29.02	2
Case temperature	25.00	25.00	0.000	25.00	25.00	25.00	2
	25.00	25.00	0.000	25.00	25.00	25.00	2
	25.00	25.00	0.000	25.00	25.00	25.00	2
IGBT 1, Diode 1 losses (W)							
IGBT losses	1019	1076	-57.23	0.000	1175	359.1	5
	114.7	114.7	3.965e-10	0.000	519.8	143.9	2
	712.4	741.9	-29.49	0.000	825.8	243.8	3
Diode losses	0.000	0.000	0.000	0.000	342.8	104.3	1
	0.000	0.000	0.000	0.000	146.2	36.09	5
	0.000	0.000	0.000	0.000	251.8	69.58	1
Line, IGBT and Diode current							
IGBT 1 current	372.6	388.2	-15.54	0.000	424.3	109.2	1
	372.6	388.2	-15.54	0.000	424.3	113.8	1
	372.6	388.2	-15.54	0.000	424.3	109.5	1
Diode 1 current	0.000	0.000	0.000	0.000	424.3	28.74	9
	0.000	0.000	0.000	0.000	424.3	25.80	8
	0.000	0.000	0.000	0.000	424.2	28.52	9
Output voltage	200.0	400.0	-200.0	-400.0	400.0	3.728	2
	400.0	400.0	1.128e-7	-400.0	400.0	5.218	2
	400.0	200.0	200.0	-400.0	400.0	2.899	2
Output current	372.6	388.2	-15.54	-424.3	424.3	4.965	3
	372.6	388.2	-15.54	-424.3	424.3	4.965	3
	372.6	388.2	-15.54	-424.3	424.3	4.965	3

# More Scope Functions

You can use different kind of zoom functions. Please note that (according to your hardware / internet connections etc.) the responding time might be slow.

## Free zoom:

Zoom in x and y direction possible

1

## Constrained zoom:

the whole y-axis range is fixed.  
Zoom in x direction

2

## Zoom to fit:

resets all zoom operations

3

Previous / next view



# Thank you!

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If you have any questions, please contact us.

<http://www.fujielectric.com/products/semiconductor/contact/index.html>



**FE** **Fuji Electric**  
*Innovating Energy Technology*

The logo features a stylized 'FE' in blue, where the 'E' is a circle with a horizontal line through it. The text 'Fuji Electric' is in a bold, black, sans-serif font, and the tagline 'Innovating Energy Technology' is in a black, italicized, sans-serif font. The background of the slide is a blue and white image of Earth from space, with several colorful, glowing arcs of light (yellow, orange, purple) radiating from a bright point at the bottom center.